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NEWS 5	FEB 06	Patent sequence location (PSL) data added to USGENE
NEWS 6	FEB 10	COMPENDEX reloaded and enhanced
NEWS 7	FEB 11	WTEXTILES reloaded and enhanced
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NEWS 12	FEB 23	TOXCENTER updates mirror those of MEDLINE - more precise author group fields and 2009 MeSH terms
NEWS 13	FEB 23	Three million new patent records blast AEROSPACE into STN patent clusters
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NEWS 15	MAR 06	INFADOCDB and INFAFAMDB enhanced with new display formats
NEWS 16	MAR 11	EPFULL backfile enhanced with additional full-text applications and grants
NEWS 17	MAR 11	ESBIOBASE reloaded and enhanced
NEWS 18	MAR 20	CAS databases on STN enhanced with new super role for nanomaterial substances
NEWS 19	MAR 23	CA/CAplus enhanced with more than 250,000 patent equivalents from China
NEWS 20	MAR 30	IMSPATENTS reloaded and enhanced
NEWS 21	APR 03	CAS coverage of exemplified prophetic substances enhanced
NEWS 22	APR 07	STN is raising the limits on saved answers
NEWS 23	APR 24	CA/CAplus now has more comprehensive patent assignee information
NEWS 24	APR 26	USPATFULL and USPAT2 enhanced with patent assignment/reassignment information
NEWS 25	APR 28	CAS patent authority coverage expanded
NEWS 26	APR 28	ENCOMPLIT/ENCOMPPLIT2 search fields enhanced
NEWS 27	APR 28	Limits doubled for structure searching in CAS REGISTRY

NEWS EXPRESS JUNE 27 08 CURRENT WINDOWS VERSION IS V8.3.

AND CURRENT DISCOVER FILE IS DATED 23 JUNE 2008.

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FILE COVERS 1907 - 7 May 2009 VOL 150 ISS 19
FILE LAST UPDATED: 6 May 2009 (20090506/ED)
REVISED CLASS FIELDS (/NCL) LAST RELOADED: Feb 2009
USPTO MANUAL OF CLASSIFICATIONS THESAURUS ISSUE DATE: Feb 2009

CPlus now includes complete International Patent Classification (IPC) reclassification data for the third quarter of 2008.

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    125618 LEAK?
    12648 MEMS
    353 MOEMS
    1317 MICROMETRIC
        9 MICROMETRICS
    1326 MICROMETRIC
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(MICROMETRIC OR MICROMETRICS)
25140108 PY<=2004
L1 196 (HERMETIC? OR LEAK?) AND (MEMS OR MOEMS OR MICROMETRIC) AND PY<=2004
=> s l1 and (optic? or visual?)
1222552 OPTIC?
152386 VISUAL?
L2 30 L1 AND (OPTIC? OR VISUAL?)
=> d l2 1-30 ibib abs

LI ANSWER 8 OF 30 CAPLUS COPYRIGHT 2009 ACS ON STM
 ACCESSION NUMBER: 2004-65938 CAPLUS
 DOCUMENT NUMBER: 140551743
 TITLE: Sealing of adhesive-bonded devices on wafer level
 AUTHOR(S): Charchar, Z.; Niklaus, F.; Steiner, M.
 CORPORATE SOURCE: Microelectronics and System,
 Department of Electrical and Computer Engineering,
 University of Illinois at Urbana-Champaign, Royal Institute of Technology
 (KTH), Stockholm, SE-10044, Sweden
 DOCUMENT TYPE: Patent Application, U.S. Patent and Trademark Office
 PUBLISHER: Elsevier Science B.V.
 LANGUAGE: English
 AB In this paper, we present a low temperature wafer-level encapsulation
 technique to hermetically seal adhesive-bonded microsystem structures by
 cladding the adhesive with an additional diffusion barrier. Two wafers
 coated with a polymer for MEMS devices were bonded together using
 bismacryloyl anhydride (BMA). The devices were sealed by a combined dicing and
 self-aligning etching technique and by finally coating the structures
 with evaporated gold or TiCNW silicon nitride. The sealing layer was
 visually checked by SEM and helium leak tests were carried out.
 Devices sealed with silicon nitride and with a 1.5 μ m thickness of the sealing
 layer showed a leak rate of 10^{-7} cc/s, which is 14 times higher than
 the background level. Devices of the same size without damage in the
 sealing layer had a leak rate of 10^{-9} cc/s. The leak rate of the BMA-bonded
 structures was 10^{-9} cc/s, with evaporated gold as cladding layer revealed
 leaking cracks in the film even up to a gold thickness of 5 μ m.
 The sealing technique with silicon nitride shows a significant
 improvement
 of the hermeticity properties of adhesive-bonded cavities.
 The technique is also found to be suitable for applications with certain
 demands on gas-tightness.
 REFERENCE COUNT: 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR THIS
 RECORD. ALL CITATIONS AVAILABLE IN THE RE
 FORMAT

LI ANSWER 10 OF 30 CAPLUS COPYRIGHT 2009 ACS ON STM
 ACCESSION NUMBER: 2003-05308 CAPLUS
 DOCUMENT NUMBER: 140551743
 TITLE: Methods for depositing, releasing, and packaging
 microelectromechanical devices on wafers substrates
 INVENTOR(S): Patel, Satyadev; Huber, Andrew; Richards, Peter;
 Shi, Rongping; Chiang, Steven; Dubois, Robert, Jr.;
 O'Neil, Michael; Vining, Dietrich; Sun, Anthony;
 Chen, Hungyu; Han, Yea
 PATENT ASSIGNEE(S): Bell Microelectronics, Inc.
 SOURCE: U.S. Patent and Trademark Office
 DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY ACC. GEN. COUNT: 20
 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	PATENT
WO 200305308	A1	2003-0518743	200306111	2003-0518743
US 200305308	A2	2003-0518743	200306111	2003-0518743
EP 120333744	A2	2003-0518743	200306111	2003-0518743
CA 2459884	A	2003-0518743	200306111	2003-0518743
JP 2003051408	A	2003-0518743	200306111	2003-0518743
EP 1774643	A3	2003-0518743	200306111	2003-0518743
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EP 1774643	A2	2003-0518743	200306111	

L3 ANSWER 11 OF 30 CAPLOS COPYRIGHT 2009 ACS ON STN
 ACCESSION NUMBER: 200903193755 CAPLOS
 DOCUMENT NUMBER: 140-311594
 TITLE: Beginning-to-end wafer bonding for advanced optical systems
 AUTHOR(S): F. E. Parsad, W. J. Lunder, Pauli Deyar, Steven W. Wimpfinger, and Markus K. K. Gross
 CORPORATE SOURCE: SPIE-The International Society for Optical Engineering (2003), D1770(Radiant Laser Structure, and Diffractive Optical Systems 2003), 31-38
 PUBLISHER: SPIE-The International Society for Optical Engineering
 DOCUMENT TYPE: Journal; General Review
 LANGUAGE: English
 ABSTRACT: A review. The old adage 'work smarter, not harder' is certainly applicable to today's optical system design. To survive the current economic conditions, high volume manufacturers must get optimum performance and yield from each design and optimized component. Wafer bonding and its numerous variants, is entering mainstream production environments by providing solutions throughout the product flow. For example, SOI (Si on insulator) and other laminated materials such as GaN/Al are used as cost effective alternatives to nol. epitaxy for high volume manufacturing. In addition, hybrid dielectric and semiconductor fabrication technology wafer bonding is used extensively to allow fragile compound semiconductors to be attached to rigid support wafers. This allows for front side and backside processing with a reduction in wafer breakage and cost. Wafer bonding is also used to attach compound semiconductors to each other or Si to completely integrate optical components and logic. Wafer bonding is also used to attach optical components to substrates used for waveguide formation and, when combined with vacuum sealing, highest performance is achieved for r.f. resonators. Finally, many of the latest optoelectronic solder and wafer bonding technologies are finding application in low temperature applications such as optical disk drives and packages. Through clever application of these bonding methods, throughput increases and reduction in fabrication complexity give a clear edge in the market place. This presentation will provide guidelines and process steps needed to design wafer-to-wafer bonding technologies into the high volume manufacturing environment.
 REFERENCE COUNT: 3 THERE ARE 3 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE REFORMAT

L3 ANSWER 12 OF 30 CAPLOS COPYRIGHT 2009 ACS ON STN
 ACCESSION NUMBER: 200903193756 CAPLOS
 DOCUMENT NUMBER: 140-311594
 TITLE: Packaging of optical MEMS devices
 AUTHOR(S): L. M. Hwang, S. K. Ramsey, David A. J. Holle, Christian A. O'Neill, Steven P. Nguyen, Khanh C. Tran, and Michael J. Riedel
 CORPORATE SOURCE: Lucent Technologies Bell Labs, Murray Hill, NJ, 07914, USA
 SOURCE: Journal of Electronic Packaging (2003), 125(3), 323-328
 PUBLISHER: American Society of Mechanical Engineers
 DOCUMENT TYPE: Journal
 LANGUAGE: English
 ABSTRACT: Recently, optical MEMS devices have gained considerable attention in the telecommunications industry—particularly in optical switches and optical routers. Since optical MEMS are micro-systems which rely on high precision, high alignment, and high reliability in close proximity, these packaging devices pose some unique packaging challenges yet to be addressed by the general packaging industry. Optical MEMS devices are required to be hermetically sealed, and also, access, hermeticity, mechanical strength, dimensional stability, and long-term reliability. Hermetic optical MEMS devices are often required to be mounted on a reaction coated window, and ever-increasing clso. I/O count has prompted the use of higher substrate/package technologies. Taking these requirements into consideration, we have developed a new packaging technology, namely high-temperature co-fired ceramic (HTCC), low-temperature co-fired ceramic (LTCC), and thin-film ceramic technologies. In this paper, we describe some optical MEMS packages designed using these three substrate designs, package materials, ease of integration and assembly.
 REFERENCE COUNT: 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE REFORMAT

L3 ANSWER 12 OF 30 CAPLOS COPYRIGHT 2009 ACS ON STN
 ACCESSION NUMBER: 200903193757 CAPLOS
 DOCUMENT NUMBER: 140-3126140
 TITLE: Drift-free, 10000g mechanical shock tolerant single-crystal silicon two-axis MEMS tilting microconnect
 AUTHOR(S): Gasparyan, A.; Shao, W.; Arney, S.; Akayak, V.; Sizemore, M.; Eri, Parsad, F.; Chang, E.; Kim, J.; Cutts, J.; Hwang, L.; Nguyen, S.; Tran, K.; Holle, C.; O'Neill, A.; Bell Laboratories, Lucent Technologies, Murray Hill, NJ, 07974, USA
 CORPORATE SOURCE: Optical Fiber Communications Conference (2003), PD1-1-10
 SOURCE: Optical Fiber Communications Conference (2003), PD1-1-10
 PUBLISHER: Optical Society of America
 DOCUMENT TYPE: Conference
 LANGUAGE: English
 ABSTRACT: The authors report drift-free two-axis tilting MEMS mirrors fabricated from single crystal Si. These micromirrors survive 10000g shock and exhibit angular stability better than 4 millidegrees under constant vibration. The authors believe that these arrays were used to build a low-loss monolithic 1000x1000-port optical cross-connect switch.
 REFERENCE COUNT: 10 THERE ARE 10 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE REFORMAT

L3 ANSWER 14 OF 30 CAPLOS COPYRIGHT 2009 ACS ON STN
 ACCESSION NUMBER: 200903193759 CAPLOS
 DOCUMENT NUMBER: 140-3126140
 TITLE: Packaging micromechanical devices
 AUTHOR(S): L. M. Hwang, S. K. Ramsey, David Andrew
 CORPORATE SOURCE: Lucent Technologies Inc., USA
 SOURCE: U.S., 6 pp
 DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY ACC. NUM. COUNT: 1
 PARENT INFORMATION:
 PATENT NO. KIND DATE APPLICATION NO. DATE
 66203182 RE 20020905 US 2002-97072 20020312
 <--
 PRIORITY APPL. INFO.: US 2002-97072 20020312
 ABSTRACT: The specification describes a packaging arrangement for micro-electromechanical systems (MEMS). The MEMS devices are mounted on a ceramic platform and are then packaged in a hybrid package. The hybrid package includes a polymer printed wiring board and a ceramic insert as the primary MEMS device enclosure. The ceramic insert is mounted on a polymer printed wiring board, which provides electrical connection to the MEMS device and the ceramic insert. Optical access to the MEMS device is through a transparent window that may be hermetically sealed to the ceramic insert. The MEMS device is mounted in an enclosure for the MEMS device array substantially eliminates thermal noise and vibration. The MEMS device array has a high performance for the elements that require it. The main interconnection and routing function, implemented using standard epoxy resin printed circuit technology, yields high interconnection versatility and performance at low cost.
 REFERENCE COUNT: 8 THERE ARE 8 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE REFORMAT

13 ANSWER 19 OF 30 CAPLOS COPYRIGHT 2009 ACS ON STN
 ACCESION NUMBER: 2002-956797 CAPLOS
 DOCUMENT NUMBER: 13842793
 TITLE: Radio frequency microelectromechanical systems
 devices
 on low-temperature co-fired ceramic substrates
 Ongur, Mahmut; Buff, Michael A.
 CORPORATE SOURCE: Corporation for National Research Initiatives, USA
 SOURCE: *Proc. Int. Conf. on Micro/Nano Eng.*, 141 pp.
 DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY ACC. NUM. COUNT: 1
 PATENT INFORMATION:

PATENT NO.	TYPE	DATE	APPLICATION NO.	DATE
WO 2002031646	A1	20021128	WO 2002-0515602	20020520
US 2002031646	A1	20020130		
EP 13842793	A1	20020130		
CA 2442262	A1	20020130		
DE 102002032009	A1	20020130	WO 2002-052009	20020520
US 2002032009	A1	20020130	US 2002-147907	20020520
US 6015739	R2	20041109		
US 20050167047	A1	20050604	US 2005-643986	20050917
US 20042262645	A1	20041109	US 2004-835590	20040430
US 20023232009	A1	20020130	US 2002-052009	20020520

AB: A phased-array antenna system and other types of radio frequency (RF) devices and systems using microelectronics, switches (MEMS) and low-temperature co-fired ceramic (LTCC) technol. and a method of fabrication. The phased-array antenna system and other types of RF devices are disclosed. Each antenna or other type of device includes a substrate, a metalized module, a metalized module having a MEMS fabricated on 1 of the modules. Once fabrication of the MEMS device is completed, the 2 ceramic modules are bonded together, forming a single monolithic module. The metalized modules are allowing electrical connections between all device layers. The bottom ceramic module has also cavities at the backside for mounting integrated circuitts.

13 ANSWER 20 OF 30 CAPLOS COPYRIGHT 2009 ACS ON STN
 ACCESION NUMBER: 2002-956798 CAPLOS
 DOCUMENT NUMBER: 13842793
 TITLE: Low-temperature anodic bonding facilitated by
 low-temperature glass on borosilicate glass
 AUTHOR(S): Watson, Chad S.; Hirschfeld, Deidre A.; Schubert, W.
 CORPORATE SOURCE: New Mexico Institute of Mining and Technology,
 Socorro, NM, 87801, USA
 SOURCE: Ceramic Engineering and Science Proceedings (2002), 23(1), 103-106
 CODEN: CESPDM; ISSN: 0895-6219
 PUBLISHER: American Ceramic Society
 DOCUMENT TYPE: Journal
 LANGUAGE: English
 AB: An optical waveguide hermetic packaging of
 microelectromech. systems (MEMS) devices was the need for lower
 glass-to-silicon bonding temp. Ion exchange, a technique traditionally
 used to modify the surface of glass, was used to bond glass to
 glass to silicon. Lithium ion exchange techniques were used to lower the
 anodic bonding temperature to as low as 250° using a point-cathode configuration
 and to 200° using a sun-bender.
 REFERENCE COUNT: 16 THERE ARE 16 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE

13 ANSWER 19 OF 30 CAPLOS COPYRIGHT 2009 ACS ON STN (Continued)
 The internal layers are formed using conductive, resistive and high-k
 dielectric materials available in sput. RIE, LIGA fabrication and low-voids dielect.
 LTCC tape materials
 REFERENCE COUNT: 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR THIS
 RECORD. ALL CITATIONS AVAILABLE IN THE RE

FORMAT

13 ANSWER 21 OF 30 CAPLOS COPYRIGHT 2009 ACS ON STN
 ACCESION NUMBER: 2002-784719 CAPLOS
 DOCUMENT NUMBER: 13842351
 TITLE: Performance and reliability of a MEMS-based
 optical filter operating in the 1565
 nm-1525 nm wavelength range
 AUTHOR(S): Srinivas, T. S.; Straub, B.; Peppas, S.; Baliga, A.;
 Alvarado, A.; Datta, D.; Wang, P.; Azani,
 M. J.
 CORPORATE SOURCE: Boston Optical Components, Metal Networks,
 Wilmington, MA, 01887, USA
 SOURCE: *Proc. International Symposium Proceedings (2002)*, 723(Materials and Devices for
 Optoelectronics and Microphotronics), 149-154
 CODEN: ISOPDM; ISSN: 1063-6172
 PUBLISHER: Materials Research Society
 DOCUMENT TYPE: Journal
 LANGUAGE: English
 AB: This paper describes the results of extensive performance and reliability
 characterization of a 1565 nm-1525 nm wavelength range
 optical filter. The device possesses a high-finesse Fabry-Perot
 etalon with one flat and one curved dielectric mirror. The curved mirror is
 mounted on a piezoelectric transducer (PZT) which is used to tune the cavity.
 The device is bonded to a substrate using a metalized membrane and a
 node fiber inside a hermetic package. Extensive performance
 characterization (over operating temperature range) was performed on the
 package. The characterization includes insertion loss, filter line-width and side mode
 suppression. The device also exhibits high reliability by operating the
 MEMS structure to a very large number of actuations at an elevated
 temperature both inside the package and on a test board. The MEMS
 structure did not exhibit any failure mode or any degradation throughout
 failures. Package level reliability testing conforming to Telcordia
 stds.
 indicated that key device parameters including insertion loss, filter
 line-width and tuning characterization did not change measurably over the
 duration of the test.
 REFERENCE COUNT: 7 THERE ARE 7 CITED REFERENCES AVAILABLE FOR THIS
 RECORD. ALL CITATIONS AVAILABLE IN THE RE

FORMAT

L2 ANSWER 22 OF 30 CAPLUS COPYRIGHT 2009 ACS ON STN
 ACCESSION NUMBER: 2002-5599014 CAPLUS
 DOCUMENT NUMBER: 10200205599014
 TITLE: A high reliability, reworkable, fluorinated poly(phenylene ether ketone) (LTF-PER) coating for microelectronic and optical applications

AUTHOR(S): Pike, R. T.; Adkins, C. L.; Newton, C. M.; Bryant, C.
 CORPORATE SOURCE: Microsystems Technology Group, Xaxis Corporation, Palm Bay, FL 32902, USA

SOURCE: Proceedings of the Annual Advanced Packaging Materials Symposium, 8th, Stone Mountain, GA, United States, Mar. 3-6, 2002 (2002), 324-330.
 Institute of Electrical and Electronics Engineers

Now
 York, NY
 CONF: 6/27/07 ISBN: 0-7803-7434-7
 DOCUMENT TYPE: Conference
 LANGUAGE: English
 AS A fluorinated poly(phenylene ether ketone) (LTF-PER) encapsulant was identified as a high performance chemical reworkable thermoplastic with near hermetic protection. The LTF-PER has legacy as a high-reliability microelectronic packaging base for GaAs die and microelectronics packages including PIM, C39, PCD, C08, SCM, MCM, and MHDs. It has recently been discovered that the LTF-PER coating is a peripheral packaging candidate for optical applications. The LTF-PER coating has a high refractive index (>1.6) and transmittance from 2000-3200 nm (>97% moisture absorption, and no

failure at 85°/85% RH/1000 h) and handle ATC 2.4 TMA. The low water absorption and long-term stability of the LTF-PER fluoropolymer presents a novel approach for packaging optical systems that can be implemented in high volume.

REFERENCE COUNT: 4 THERE ARE 4 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE

FORMAT

L2 ANSWER 23 OF 30 CAPLUS COPYRIGHT 2009 ACS ON STN
 ACCESSION NUMBER: 2002-665131 CAPLUS
 DOCUMENT NUMBER: 1020020665131
 TITLE: A novel optical fiber interconnection apparatus and method of using the same

INVENTOR(S): Daneman, Michael J.; Behr, Behrangular Wall, Franklin
 PATENT ASSIGNEE(S): Xaxis Corporation, Palm Bay, FL, USA
 SOURCE: U.S. Pat. Appl. Publ.

DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY: 1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11, 12, 13, 14, 15, 16, 17, 18, 19, 20, 21, 22, 23, 24, 25, 26, 27, 28, 29, 30, 31, 32, 33, 34, 35, 36, 37, 38, 39, 40, 41, 42, 43, 44, 45, 46, 47, 48, 49, 50, 51, 52, 53, 54, 55, 56, 57, 58, 59, 60, 61, 62, 63, 64, 65, 66, 67, 68, 69, 70, 71, 72, 73, 74, 75, 76, 77, 78, 79, 80, 81, 82, 83, 84, 85, 86, 87, 88, 89, 90, 91, 92, 93, 94, 95, 96, 97, 98, 99, 100, 101, 102, 103, 104, 105, 106, 107, 108, 109, 110, 111, 112, 113, 114, 115, 116, 117, 118, 119, 120, 121, 122, 123, 124, 125, 126, 127, 128, 129, 130, 131, 132, 133, 134, 135, 136, 137, 138, 139, 140, 141, 142, 143, 144, 145, 146, 147, 148, 149, 150, 151, 152, 153, 154, 155, 156, 157, 158, 159, 160, 161, 162, 163, 164, 165, 166, 167, 168, 169, 170, 171, 172, 173, 174, 175, 176, 177, 178, 179, 180, 181, 182, 183, 184, 185, 186, 187, 188, 189, 190, 191, 192, 193, 194, 195, 196, 197, 198, 199, 200, 201, 202, 203, 204, 205, 206, 207, 208, 209, 210, 211, 212, 213, 214, 215, 216, 217, 218, 219, 220, 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595, 596, 597, 597, 598, 599, 599, 600, 601, 602, 603, 604, 605, 606, 607, 608, 609, 609, 610, 611, 612, 613, 614, 615, 616, 617, 617, 618, 619, 619, 620, 621, 622, 623, 624, 625, 626, 627, 627, 628, 629, 629, 630, 631, 632, 633, 634, 635, 636, 637, 637, 638, 639, 639, 640, 641, 642, 643, 644, 645, 646, 646, 647, 648, 648, 649, 650, 651, 652, 653, 654, 655, 656, 657, 657, 658, 659, 659, 660, 661, 662, 663, 664, 665, 666, 667, 667, 668, 669, 669, 670, 671, 672, 673, 674, 675, 675, 676, 677, 677, 678, 679, 679, 680, 681, 682, 683, 684, 685, 686, 687, 687, 688, 689, 689, 690, 691, 692, 693, 694, 695, 696, 697, 697, 698, 699, 699, 700, 701, 702, 703, 704, 705, 706, 707, 708, 709, 709, 710, 711, 712, 713, 714, 715, 716, 717, 718, 719, 719, 720, 721, 722, 723, 724, 725, 726, 727, 727, 728, 729, 729, 730, 731, 732, 733, 734, 735, 736, 737, 737, 738, 739, 739, 740, 741, 742, 743, 744, 745, 746, 746, 747, 748, 748, 749, 750, 751, 752, 753, 754, 755, 756, 757, 757, 758, 759, 759, 760, 761, 762, 763, 764, 765, 766, 767, 767, 768, 769, 769, 770, 771, 772, 773, 774, 775, 775, 776, 777, 778, 778, 779, 779, 780, 781, 782, 783, 784, 785, 786, 787, 787, 788, 789, 789, 790, 791, 792, 793, 794, 795, 796, 797, 797, 798, 799, 799, 800, 801, 802, 803, 804, 805, 806, 807, 808, 809, 809, 810, 811, 812, 813, 814, 815, 816, 817, 817, 818, 819, 819, 820, 821, 822, 823, 824, 825, 826, 827, 827, 828, 829, 829, 830, 831, 832, 833, 834, 835, 836, 837, 837, 838, 839, 839, 840, 841, 842, 843, 844, 845, 846, 846, 847, 848, 848, 849, 850, 851, 852, 853, 854, 855, 856, 857, 857, 858, 859, 859, 860, 861, 862, 863, 864, 865, 866, 867, 867, 868, 869, 869, 870, 871, 872, 873, 874, 875, 875, 876, 877, 877, 878, 879, 879, 880, 881, 882, 883, 884, 885, 886, 887, 887, 888, 889, 889, 890, 891, 892, 893, 894, 895, 896, 897, 897, 898, 899, 899, 900, 901, 902, 903, 904, 905, 906, 907, 907, 908, 909, 909, 910, 911, 912, 913, 914, 915, 915, 916, 917, 917, 918, 919, 919, 920, 921, 922, 923, 924, 925, 926, 927, 927, 928, 929, 929, 930, 931, 932, 933, 934, 935, 936, 937, 937, 938, 939, 939, 940, 941, 942, 943, 944, 945, 946, 946, 947, 948, 948, 949, 950, 951, 952, 953, 954, 955, 956, 957, 957, 958, 959, 959, 960, 961, 962, 963, 964, 965, 966, 967, 967, 968, 969, 969, 970, 971, 972, 973, 974, 975, 975, 976, 977, 977, 978, 979, 979, 980, 981, 982, 983, 984, 985, 986, 987, 987, 988, 989, 989, 990, 991, 992, 993, 994, 995, 996, 997, 997, 998, 999, 999, 1000, 1001, 1002, 1003, 1004, 1005, 1006, 1007, 1008, 1009, 1009, 1010, 1011, 1012, 1013, 1014, 1015, 1016, 1017, 1017, 1018, 1019, 1019, 1020, 1021, 1022, 1023, 1024, 1024, 1025, 1026, 1027, 1027, 1028, 1029, 1029, 1030, 1031, 1032, 1033, 1034, 1034, 1035, 1036, 1036, 1037, 1038, 1038, 1039, 1040, 1040, 1041, 1042, 1042, 1043, 1044, 1044, 1045, 1046, 1046, 1047, 1048, 1048, 1049, 1050, 1050, 1051, 1052, 1052, 1053, 1054, 1054, 1055, 1056, 1056, 1057, 1058, 1058, 1059, 1060, 1060, 1061, 1062, 1062, 1063, 1064, 1064, 1065, 1066, 1066, 1067, 1068, 1068, 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1161, 1161, 1162, 1162, 1163, 1163, 1164, 1164, 1165, 1165, 1166, 1166, 1167, 1167, 1168, 1168, 1169, 1169, 1170, 1170, 1171, 1171, 1172, 1172, 1173, 1173, 1174, 1174, 1175, 1175, 1176, 1176, 1177, 1177, 1178, 1178, 1179, 1179, 1180, 1180, 1181, 1181, 1182, 1182, 1183, 1183, 1184, 1184, 1185, 1185, 1186, 1186, 1187, 1187, 1188, 1188, 1189, 1189, 1190, 1190, 1191, 1191, 1192, 1192, 1193, 1193, 1194, 1194, 1195, 1195, 1196, 1196, 1197, 1197, 1198, 1198, 1199, 1199, 1200, 1200, 1201, 1201, 1202, 1202, 1203, 1203, 1204, 1204, 1205, 1205, 1206, 1206, 1207, 1207, 1208, 1208, 1209, 1209, 1210, 1210, 1211, 1211, 1212, 1212, 1213, 1213, 1214, 1214, 1215, 1215, 1216, 1216, 1217, 1217, 1218, 1218, 1219, 1219, 1220, 1220, 1221, 1221, 1222, 1222, 1223, 1223, 1224, 1224, 1225, 1225, 1226, 1226, 1227, 1227, 1228, 1228, 1229, 1229, 1230, 1230, 1231, 1231, 1232, 1232, 1233, 1233, 1234, 1234, 1235, 1235, 1236, 1236, 1237, 1237, 1238, 1238, 1239, 1239, 1240, 1240, 1241, 1241, 1242, 1242, 1243, 1243, 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1327, 1327, 1328, 1328, 1329, 1329, 1330, 1330, 1331, 1331, 1332, 1332, 1333, 1333, 1334, 1334, 1335, 1335, 1336, 1336, 1337, 1337, 1338, 1338, 1339, 1339, 1340, 1340, 1341, 1341, 1342, 1342, 1343, 1343, 1344, 1344, 1345, 1345, 1346, 1346, 1347, 1347, 1348, 1348, 1349, 1349, 1350, 1350, 1351, 1351, 1352, 1352, 1353, 1353, 1354, 1354, 1355, 1355, 1356, 1356, 1357, 1357, 1358, 1358, 1359, 1359, 1360, 1360, 1361, 1361, 1362, 1362, 1363, 1363, 1364, 1364, 1365, 1365, 1366, 1366, 1367, 1367, 1368, 1368, 1369, 1369, 1370, 1370, 1371, 1371, 1372, 1372, 1373, 1373, 1374, 1374, 1375, 1375, 1376, 1376, 1377, 1377, 1378, 1378, 1379, 1379, 1380, 1380, 1381, 1381, 1382, 1382, 1383, 1383, 1384, 1384, 1385, 1385, 1386, 1386, 1387, 1387, 1388, 1388, 1389, 1389, 1390, 1390, 1391, 1391, 1392, 1392, 1393, 1393, 1394, 1394, 1395, 1395, 1396, 1396, 1397, 1397, 1398, 1398, 1399, 1399, 1400, 1400, 1401, 1401, 1402, 1402, 1403, 1403, 1404, 1404, 1405, 1405, 1406, 1406, 1407, 1407, 1408, 1408, 1409, 1409, 1410, 1410, 1411, 1411, 1412, 1412, 1413, 1413, 1414, 1414, 1415, 1415, 1416, 1416, 1417, 1417, 1418, 1418, 1419, 1419, 1420, 1420, 1421, 1421, 1422, 1422, 1423, 1423, 1424, 1424, 1425, 1425, 1426, 1426, 1427, 1427, 1428, 1428, 1429, 1429, 1430, 1430, 1431, 1431, 1432, 1432, 1433, 1433, 1434, 1434, 1435, 1435, 1436, 1436, 1437, 1437, 1438, 1438, 1439, 1439, 1440, 1440, 1441, 1441, 1442, 1442, 1443, 1443, 1444, 1444, 1445, 1445, 1446, 1446, 1447, 1447, 1448, 1448, 1449, 1449, 1450, 1450, 1451, 1451, 1452, 1452, 1453, 1453, 1454, 1454, 1455, 1455, 1456, 1456, 1457, 1457, 1458, 1458, 1459, 1459, 1460, 1460, 1461, 1461, 1462, 1462, 1463, 1463, 1464, 1464, 1465, 1465, 1466, 1466, 1467, 1467, 1468, 1468, 1469, 1469, 1470, 1470, 1471, 1471, 1472, 1472, 1473, 1473, 1474, 1474, 1475, 1475, 1476, 1476, 1477, 1477, 1478, 1478, 1479, 1479, 1480, 1480, 1481, 1481, 1482, 1482, 1483, 1483, 1484, 1484, 1485, 1485, 1486, 1486, 1487, 1487, 1488, 1488, 1489, 1489, 1490, 1490, 1491, 1491, 1492, 1492, 1493, 1493, 1494, 1494, 1495, 1495, 1496, 1496, 1497, 1497, 1498, 1498, 1499, 1499, 1500, 1500, 1501, 1501, 1502, 1502, 1503, 1503, 1504, 1504, 1505, 1505, 1506, 1506, 1507, 1507, 1508, 1508, 1509, 1509, 1510, 1510, 1511, 1511, 1512, 1512, 1513, 1513, 1514, 1514, 1515, 1515, 1516, 1516, 1517, 1517, 1518, 1518, 1519, 1519, 1520, 1520, 1521, 1521, 1522, 1522, 1523, 1523, 1524, 1524, 1525, 1525, 1526, 1526, 1527, 1527, 1528, 1528, 1529, 1529, 1530, 1530, 1531, 1531, 1532, 1532, 1533, 1533, 1534, 1534, 1

L1 ANSWER 29 OF 30 CAPLOS COPYRIGHT 2009 ACS ON STN
ACCESSION NUMBER: 1998-199952 CAPLOS
DOCUMENT NUMBER: 1998-199952 CAPLOS
ORIGINAL REFERENCE NO.: 128520894, 52072a
TITLE: Low temperature packaging of CMOS infrared
memories by Al-Au bonding
AUTHOR(S): Meissli, M.; Schmidberger, M.; Paal, O.; Baltes, H.
CORPORATE SOURCE: Physics and Electronics Laboratory, ETH Zurich, Zurich,
CH-8093, Swiss.
SOURCE: Proceedings - Electrochemical Society (1998
1) 147:147-154
CODEN: PECONO; ISSN: 0361-6374
PUBLISHER: Electrochemical Society
DOCUMENT TYPE: Journal
LANGUAGE: English
AB: A new low temperature packaging method for MMOS is reported. It is
demonstrated with the encapsulation of a CMOS IR detector microsystem.
AU: IR filter is directly attached to the sensor die using an on-chip Au
space frame electroplated by standard bumping technol. Delicate
components such as chemistry and IR pixels are hermetically sealed off and
effectively screened from undesired influences. The process is based on
the use of a thin Au film (10 nm) and a thin Al film (10 nm) having 1 nm of
sputtered Al. Annealing at 350° for 30 min under a bonding
pressure of 0.5 MPa produces bonds with a shear strength larger than 70
MPa. The reliability of the bonds is demonstrated by thermal cycling. Thermal
aging at 155° for 1000 h shows no changes in the interface
reliability. The new method is generally suited for integrated microsystems
requiring hermetic packaging.
REFERENCE COUNT: 12 THERE ARE 12 CITED REFERENCES AVAILABLE FOR
THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE
FORMAT

L2 ANSWER 30 OF 30 CAPLOS COPYRIGHT 2009 ACS ON STN
ACCESSION NUMBER: 1995-952034 CAPLOS
DOCUMENT NUMBER: 1995-952034 CAPLOS
ORIGINAL REFERENCE NO.: 6213H-164-170
TITLE: Design of microelectromechanical devices and systems
AUTHOR(S): Yu, Wen H.
CORPORATE SOURCE: Department of Electrical Engineering and Applied
Physics, Case Western Reserve University, Case Western Reserve University, Western
Reserve University, Cleveland, OH, 44106, USA
SOURCE: SENSORS AND ACTUATORS A-PHYSICAL (1995),
42(1), 164-170
PUBLISHER: Elsevier
DOCUMENT TYPE: Journal
LANGUAGE: English
AB: Microelectromechanical systems are to be packaged for applications. For
the design, not an after-thought. The function of the packaging is (i) to
protect the device from free radicals, (ii) to protect the device from
environment from the device operation. At present, there is no generally
applicable packaging method for microelectromechanical systems. There are basic
principles involved in packaging design. This article outlines the
fundamental requirements, design considerations, and packaging techniques
for microelectromechanical systems. The protection of the device includes:
The protection of the device includes: (i) silicon isolation and
passivation
so that the device and device structures from the penetration of moisture and ions;
sealing techniques and hermeticity measurements are important
aspects; (ii) need protection to ensure structural integrity and
dimensional stability of the device; (iii) need protection of the device
(i.e.) chemical and biological isolation and protection. It is also
necessary to protect the environment from the device materials and device operation,
so that no undesirable reaction with or contamination of the environment
occurs. This is especially important for devices used in biomedical,
pharmaceutical and food processing. Biocompatibility and contamination
must be considered in the design of the device. The design of the packaging design
requires the integration of knowledge of materials, device
characteristics, packaging and evaluation techniques. It remains as a
challenge in the MMIC field for engineers.

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=> s (hermetic? or leak?) and (semiconductor or electronic) and (optic? or visual?)  
and py<=2004  
14143 HERMETIC?  
125618 LEAK?  
690366 SEMICONDUCTOR  
104164 SEMICONDUCTORS  
718231 SEMICONDUCTOR  
          (SEMICONDUCTOR OR SEMICONDUCTORS)  
596113 ELECTRONIC  
39968 ELECTRONICS  
621902 ELECTRONIC  
          (ELECTRONIC OR ELECTRONICS)  
1222552 OPTIC?  
152386 VISUAL?  
25140108 PY<=2004  
L3      1117 (HERMETIC? OR LEAK?) AND (SEMICONDUCTOR OR ELECTRONIC) AND (OPTI  
C? OR VISUAL?) AND PY<=2004  
  
=> s l3 and (indicat? or sens?)  
2488994 INDICAT?  
1635367 SENS?  
L4      261 L3 AND (INDICAT? OR SENS?)  
  
=> d scan
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00 (Electrolyte cross-references) 57, 73
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73 Microelectromechanical devices: a new approach for opto-electronic
(microelectromechanical devices) MEMS packaging
17 Ceramics
 Electronic packaging materials
 Electronic packaging process
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 New approach for opto-electronic/MEMS packaging
 Integrated circuits
 Microelectromechanical devices: a new approach for opto-electronic/MEMS
 packaging

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=> s 14 and (gas or fluid)
      1756895 GAS
      573560 GASES
      1956527 GAS
          (GAS OR GASES)
      503698 FLUID
      207273 FLUIDS
      605029 FLUID
          (FLUID OR FLUIDS)
L5      40 L4 AND (GAS OR FLUID)

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           its structure diagram
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